CT816 Series

DC Input 4-Pin Phototransistor Optocoupler

Features

- High isolation 5000 VRMS
- CTR flexibility available see order information
- DC input with transistor output
- External Creepage ≥ 7.5mm (S/SL Type)
- External Creepage ≥ 8.0mm (SLM Type)
- Operating Temperature range - 55 ℃ to 110 ℃
- Regulatory Approvals
  - UL - UL1577 (E364000)
  - VDE - EN60747-5-5(VDE0884-5)
  - CQC – GB4943.1, GB8898
  - IEC60065, IEC60950

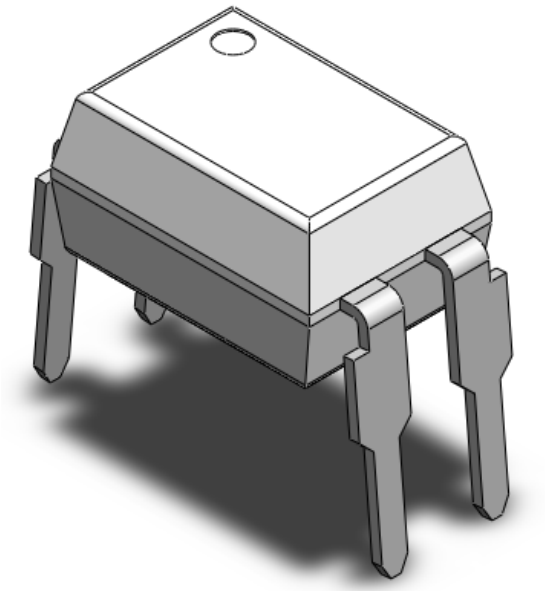
Description

The CT816 series consists of a photo transistor optically coupled to a gallium arsenide Infrared-emitting diode in a 4-lead DIP package with bending options.

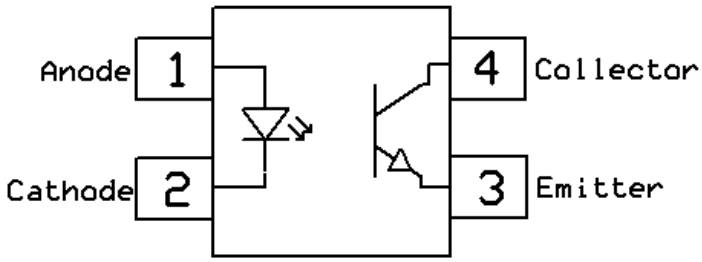
Applications

- Switch mode power supplies
- Computer peripheral interface
- Microprocessor system interface

Package Outline



Schematic



Absolute Maximum Rating at 25°C

Symbol	*Parameters*	*Ratings*	*Units*	*Notes*
V_{ISO}	Isolation voltage (AC, 1 minute)	5000	V_{RMS}	
P_{TOT}	Total power dissipation	200	mW	
T_{OPR}	Operating temperature	-55 ~ +110	°C	
T_{STG}	Storage temperature	-55 ~ +150	°C	
T_{SOL}	Soldering temperature	260	°C	
Emitter				
I_F	Forward current	60	mA	
$I_{F(TRANS)}$	Peak transient current (≤1μs P.W,300pps)	1	A	
V_R	Reverse voltage	6	V	
P_D	Emitter power dissipation	100	mW	
Detector				
P_D	Detector power dissipation	150	mW	
B_{VCEO}	Collector-Emitter Breakdown Voltage	80	V	
B_{VECO}	Emitter-Collector Breakdown Voltage	6	V	
I_C	Collector Current	50	mA	

Electrical Characteristics T_A = 25℃ (unless otherwise specified)

Emitter Characteristics

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
V_F	Forward voltage	I_F=10mA	-	1.24	1.4	V	
I_R	Reverse Current	V_R = 6V	-	-	5	μA	
C_{IN}	Input Capacitance	f= 1MHz	-	30	-	pF	

Detector Characteristics

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
B_{VCEO}	Collector-Emitter Breakdown	I_C= 100μA	80	-	-	V	
B_{VECO}	Emitter-Collector Breakdown	I_E= 100μA	6	-	-	V	
I_{CEO}	Collector-Emitter Dark Current	V_{CE}= 20V, I_F=0mA	-	-	100	nA	

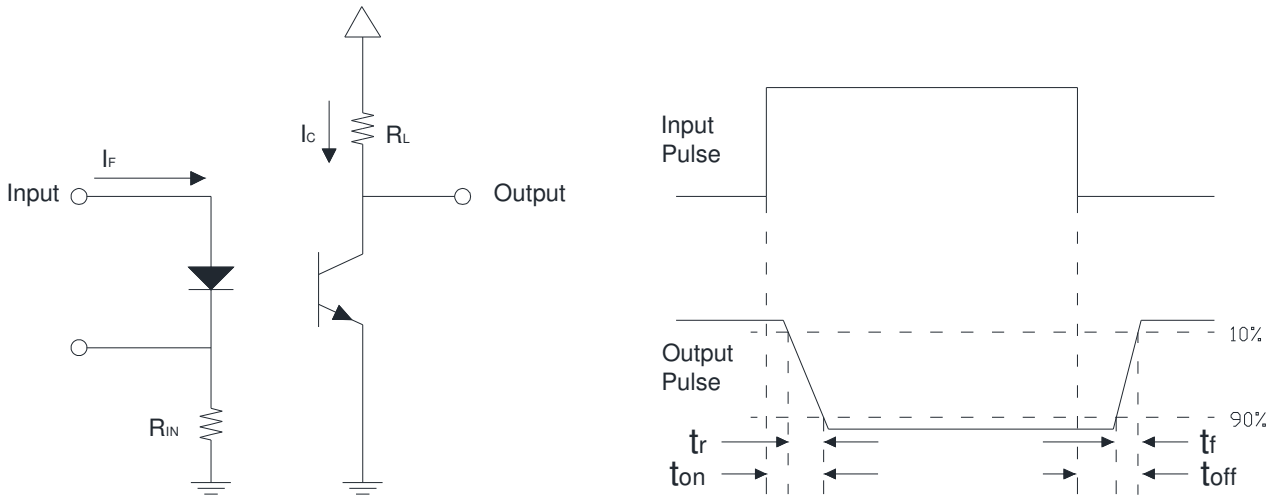
Transfer Characteristics

Symbol	Parameters		Test Conditions	Min	Typ	Max	Units	Notes
CTR	Current Transfer Ratio	CT816	I_F= 5mA, V_{CE}= 5V	50	-	600	%	
		CT816A		80	-	160		
		CT816B		130	-	260		
		CT816C		200	-	400		
		CT816D		300	-	600		
		CT816F		100	-	200		
CTR	Current Transfer Ratio	CT816I	I_F= 10mA, V_{CE}= 5V	63	-	125	%	
		CT816J		100	-	200		
		CT816K		160	-	320		
		CT816I	I_F= 1mA, V_{CE}= 5V	22	-	-		
		CT816J		34	-	-		
		CT816K		56	-	-		
$V_{CE(SAT)}$	Collector-Emitter Saturation Voltage		I_F= 20mA, I_C= 1mA	-	0.1	0.2	V	
R_{IO}	Isolation Resistance		V_{IO}= 500V_{DC}	$5x10^{10}$	-	-	Ω	
C_{IO}	Isolation Capacitance		f= 1MHz	-	0.25	1	pF	

Switching Characteristics

Symbol	*Parameters*	*Test Conditions*	*Min*	*Typ*	*Max*	*Units*	*Notes*
t_r	Rise Time	I_C= 2mA, V_{CE}= 2V, R_L= 100Ω	-	6	-	µs	
t_f	Fall Time		-	8	-		

Test Circuit



Typical Characteristic Curves

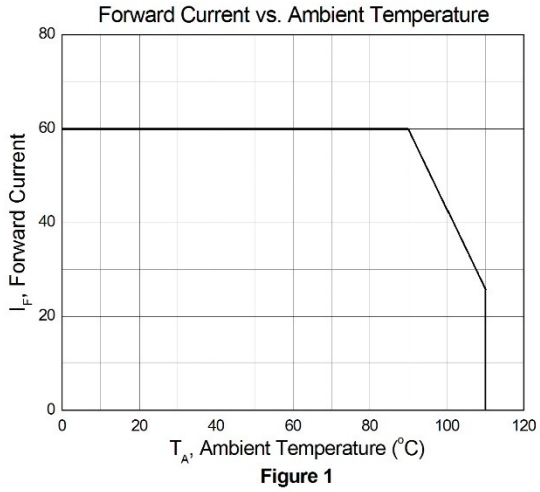


Figure 1

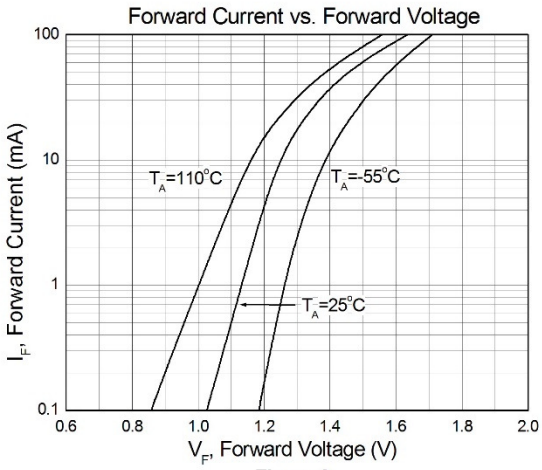


Figure 2

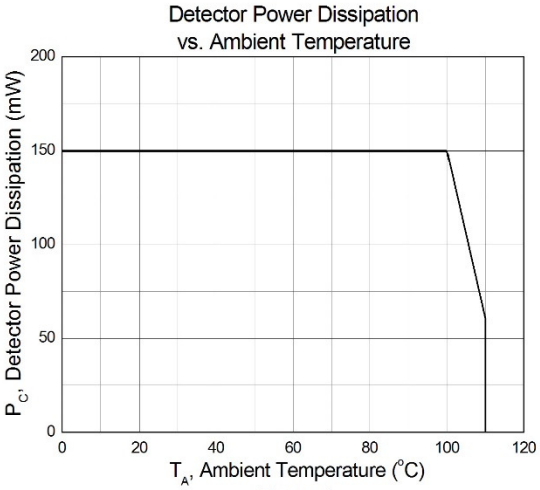


Figure 3

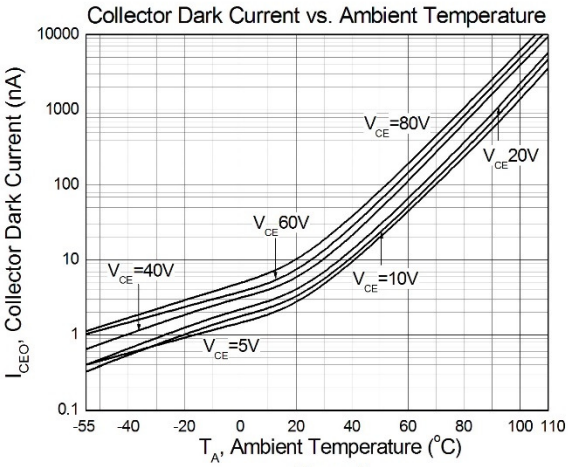


Figure 4

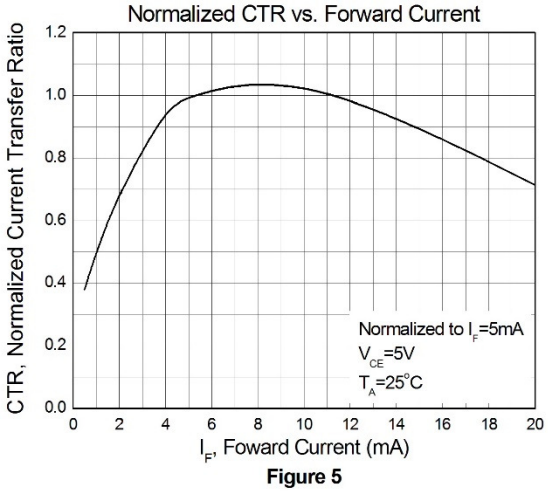


Figure 5

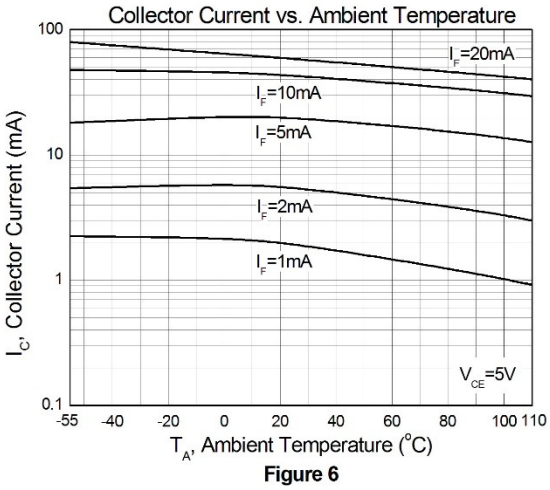


Figure 6

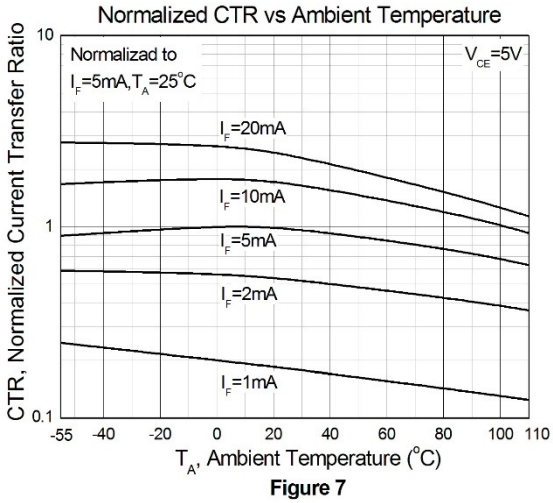


Figure 7

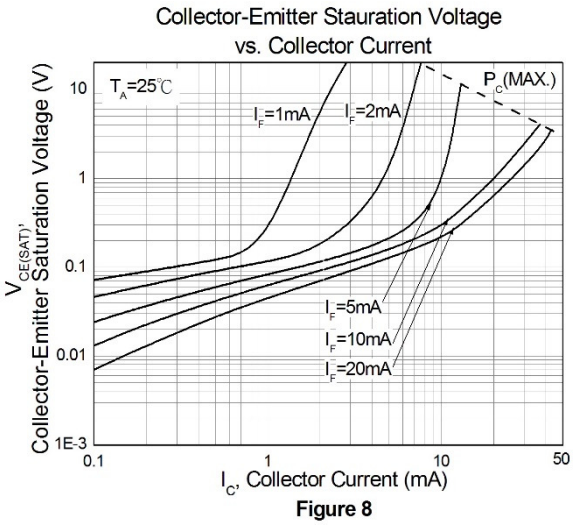


Figure 8

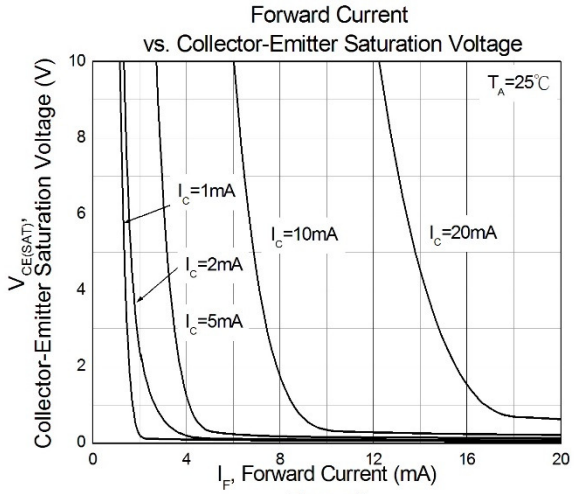


Figure 9

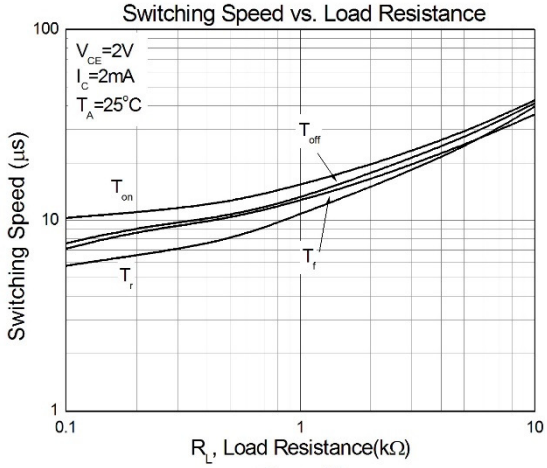


Figure 10

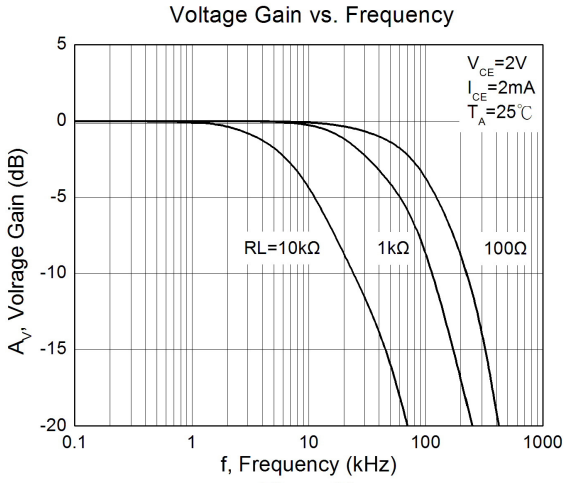
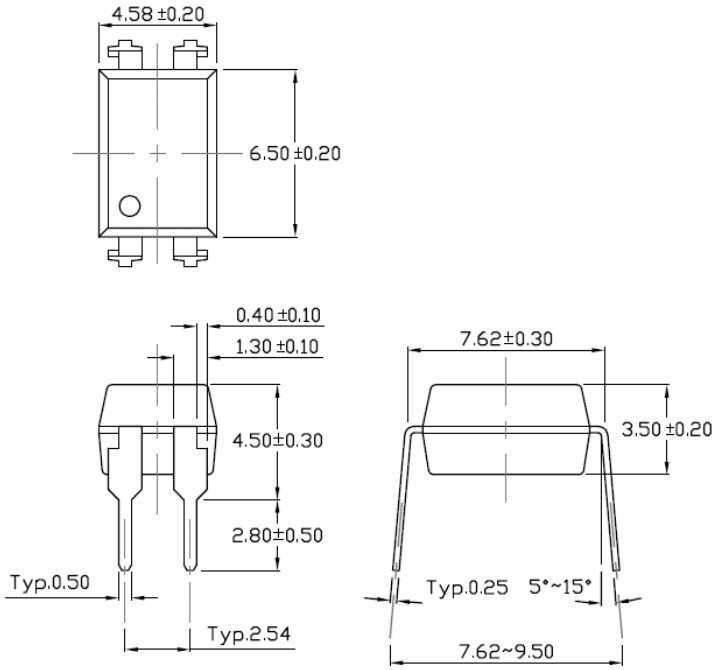


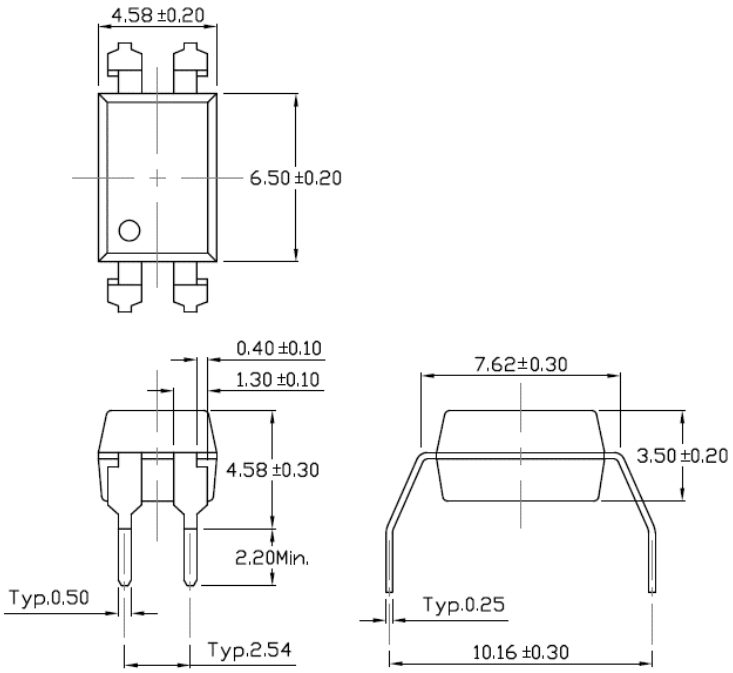
Figure 11

Package Dimension *Dimensions in mm unless otherwise stated*

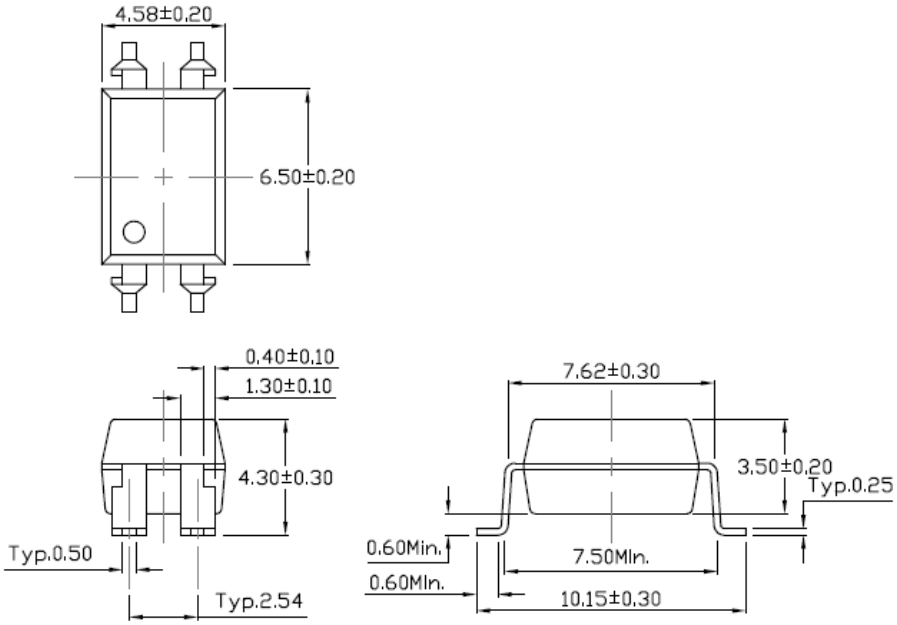
Standard DIP – Through Hole



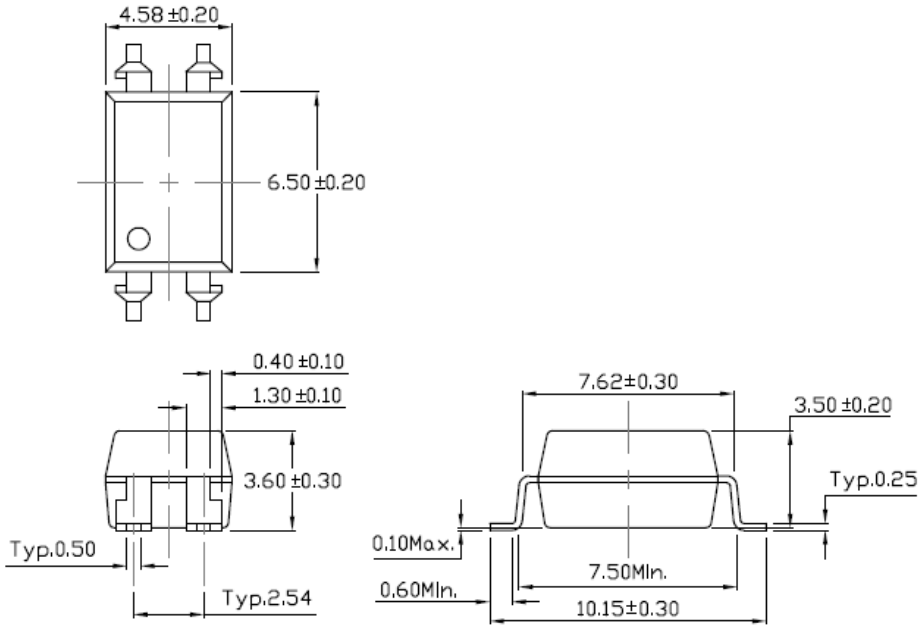
Gullwing (400mil) Lead Forming – Through Hole (M Type)



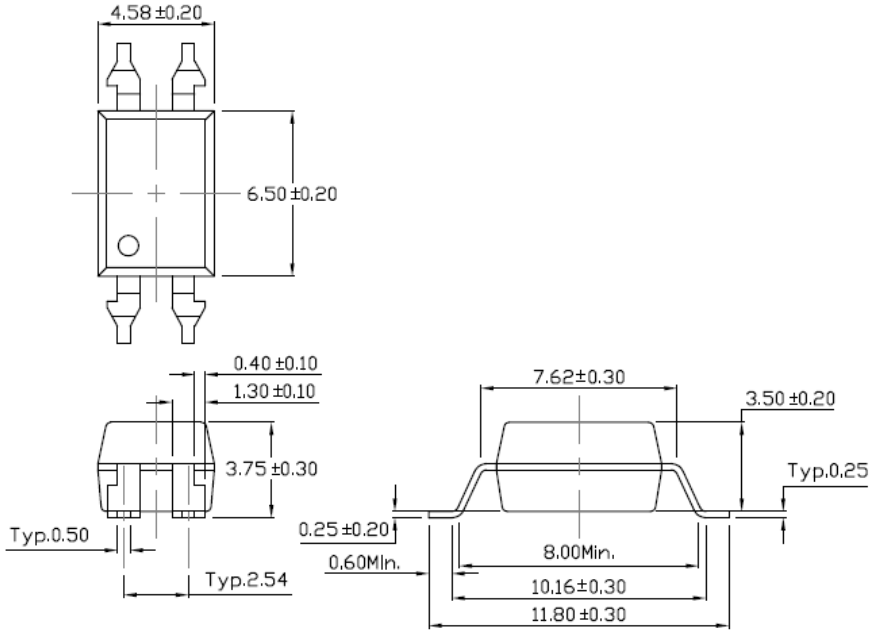
Surface Mount Lead Forming (S Type)



Surface Mount (Low Profile) Lead Forming (SL Type)

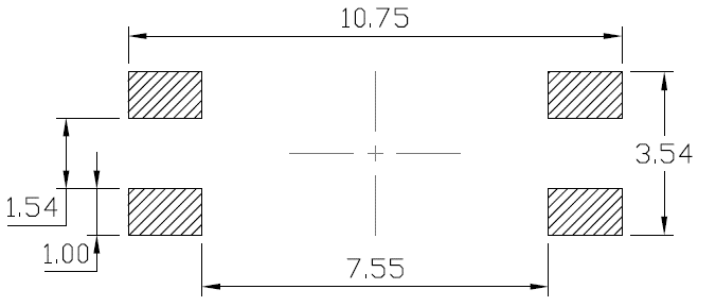


Surface Mount (Gullwing) Lead Forming (SLM Type)

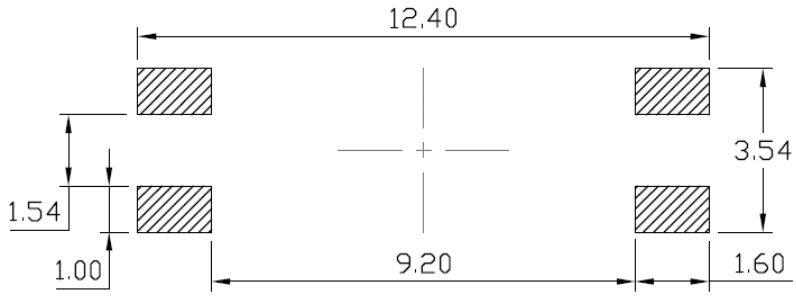


Recommended Solder Mask *Dimensions in mm unless otherwise stated*

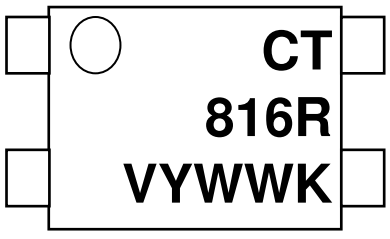
Surface Mount Lead Forming & Surface Mount (Low Profile) Lead Forming



Surface Mount (Gullwing) Lead Forming



Marking Information



Note:

CT : Denotes “CT Micro”
816 : Part Number
V : VDE Option
R : CTR Rank
Y : Fiscal Year
WW : Work Week
K : Manufacturing Code

Ordering Information

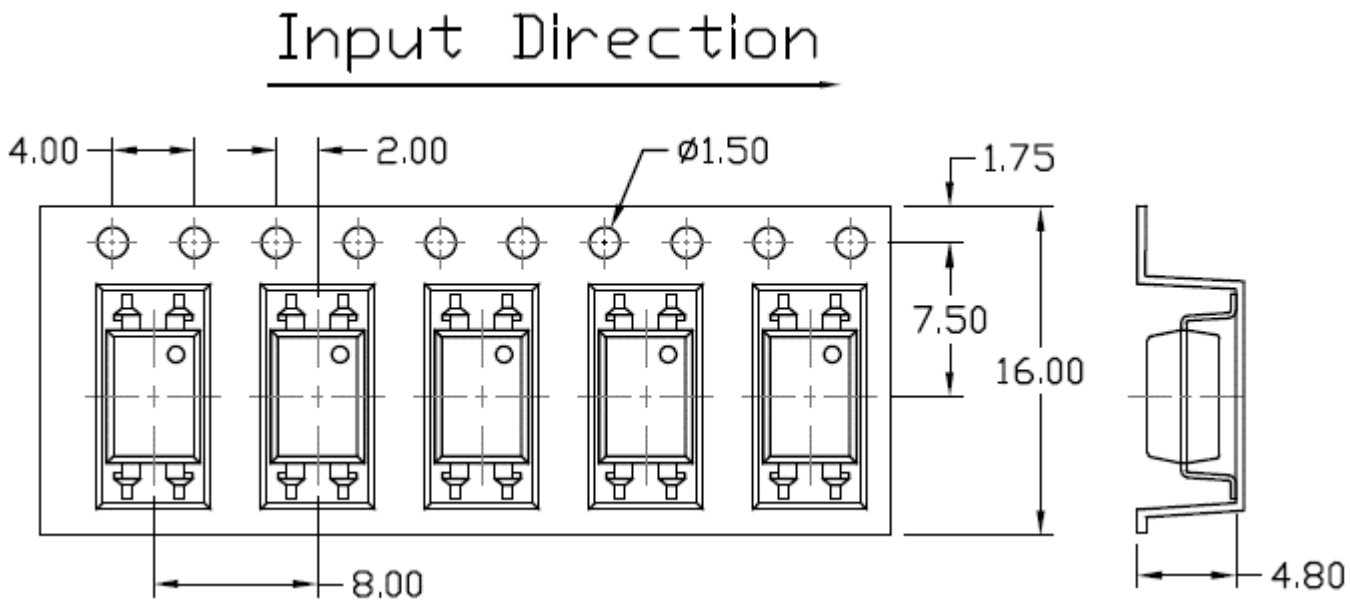
CT816X(V)(Y)(Z)-HG

X = Part No. (X=A, B, C, D, I, J, K, None)
V = VDE Option (V or None)
Y = Lead form option (S, SL, M, SLM or none)
Z = Tape and reel option (T1, T2, T3, T4 or none)
H = Lead frame option (H: Iron, None: Copper)
G= Material option (G: Green, None: Non-green)

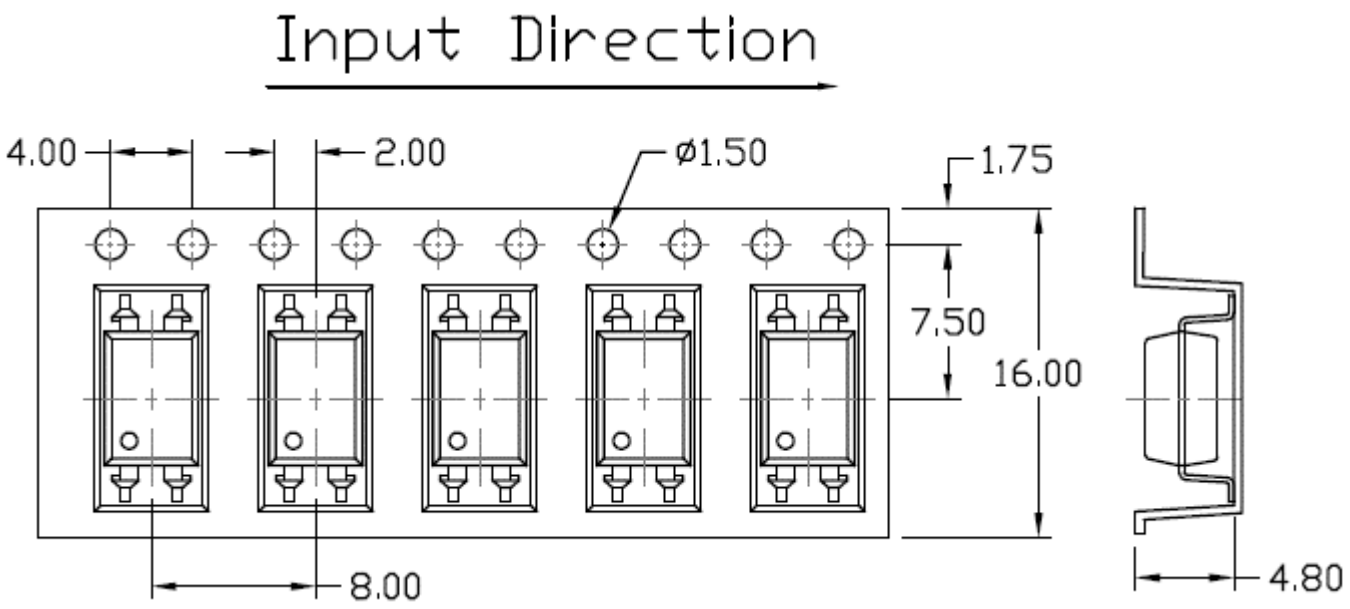
Option	***Description***	***Quantity***
None	Standard 4 Pin DIP	100 Units/Tube
M	Gullwing (400mil) Lead Forming	100 Units/Tube
S(T1)	Surface Mount Lead Forming – With Option 1 Taping	1500 Units/Reel
S(T2)	Surface Mount Lead Forming – With Option 2 Taping	1500 Units/Reel
S(T3)	Surface Mount Lead Forming – With Option 3 Taping	1000 Units/Reel
S(T4)	Surface Mount Lead Forming – With Option 4 Taping	1000 Units/Reel
SL(T1)	Surface Mount (Low Profile) Lead Forming– With Option 1 Taping	1500 Units/Reel
SL(T2)	Surface Mount (Low Profile) Lead Forming – With Option 2 Taping	1500 Units/Reel
SL(T3)	Surface Mount (Low Profile) Lead Forming– With Option 3 Taping	1000 Units/Reel
SL(T4)	Surface Mount (Low Profile) Lead Forming – With Option 4 Taping	1000 Units/Reel
SLM(T1)	Surface Mount (Gullwing) Lead Forming– With Option 1 Taping	1500 Units/Reel
SLM(T2)	Surface Mount (Gullwing) Lead Forming – With Option 2 Taping	1500 Units/Reel

Carrier Tape Specifications *Dimensions in mm unless otherwise stated*

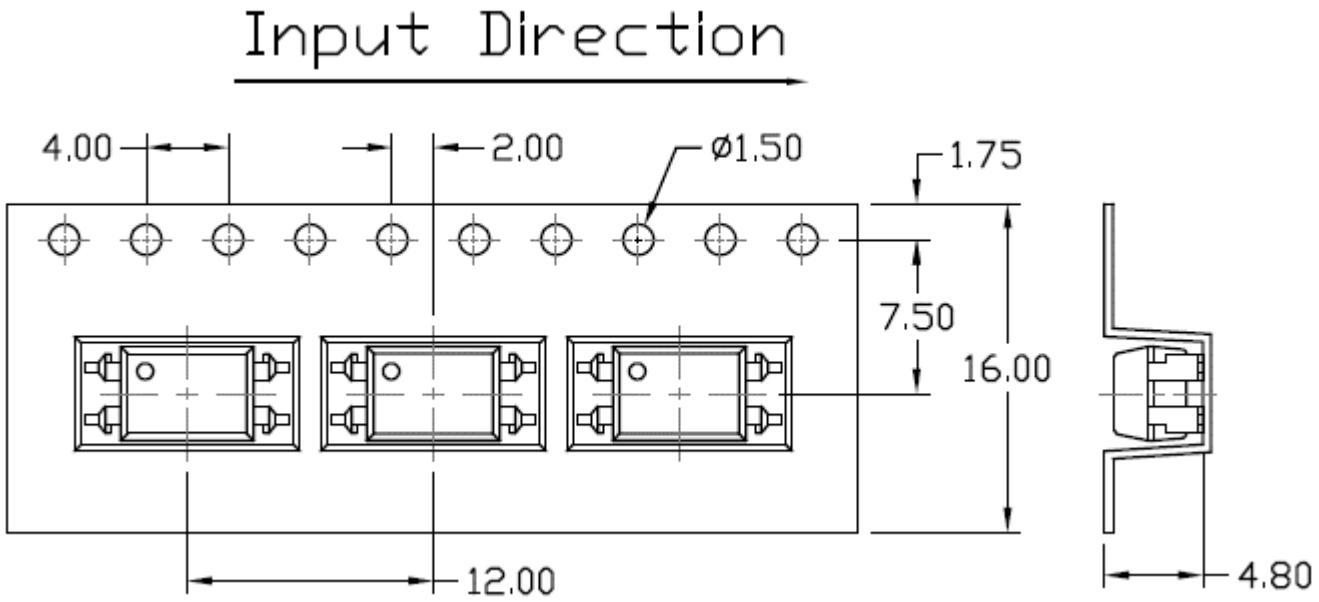
Option S(T1) & SL(T1)



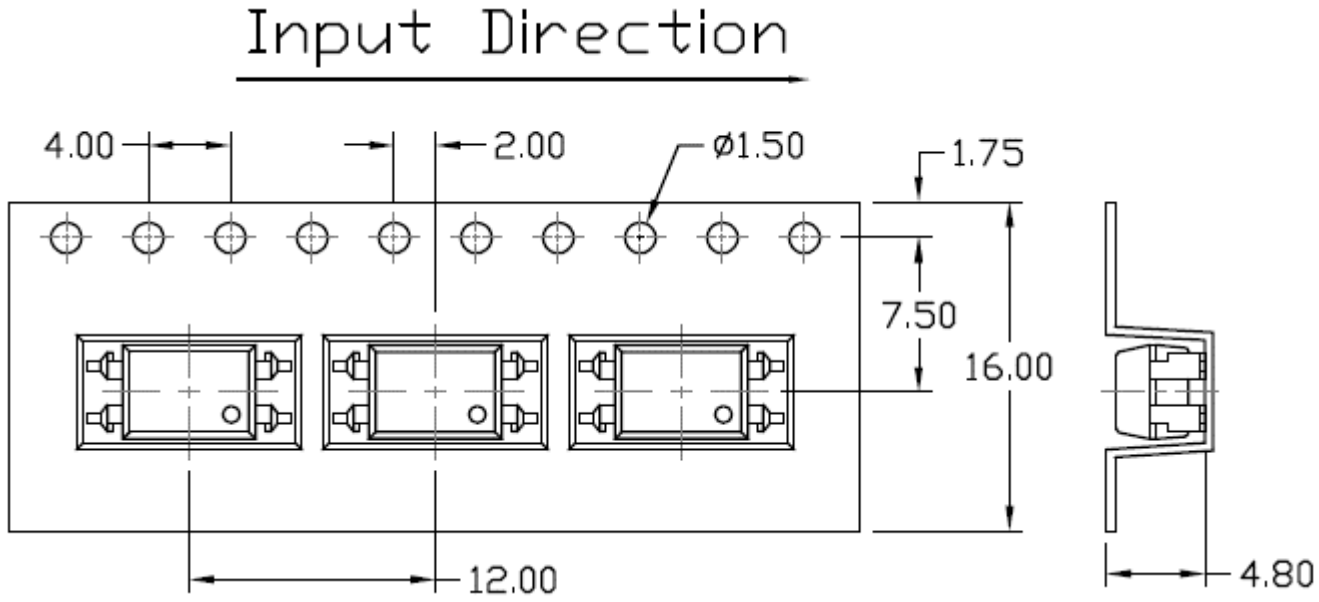
Option S(T2) & SL(T2)



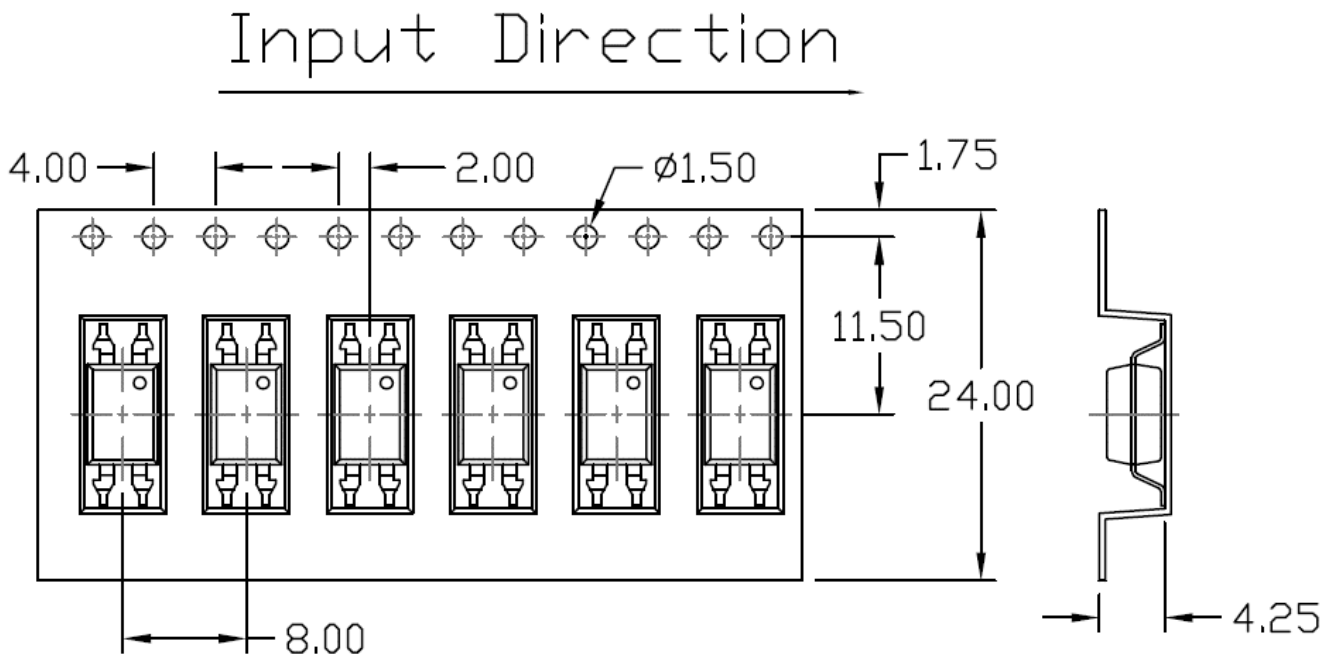
Option S(T3) & SL(T3)



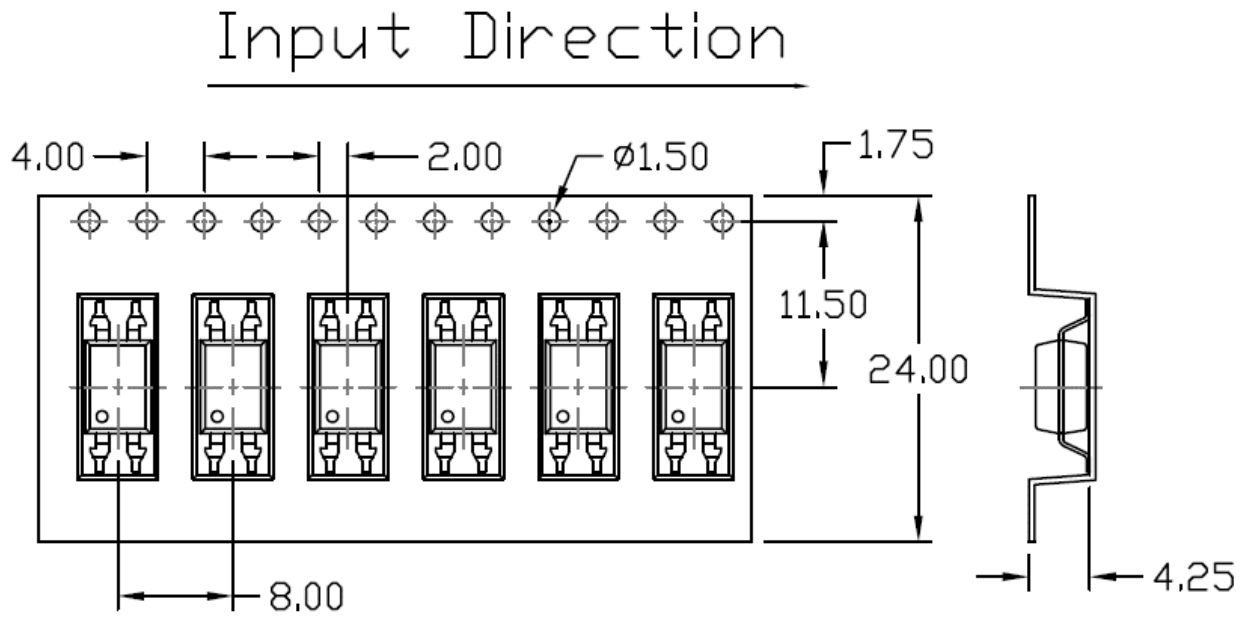
Option S(T4) & SL(T4)



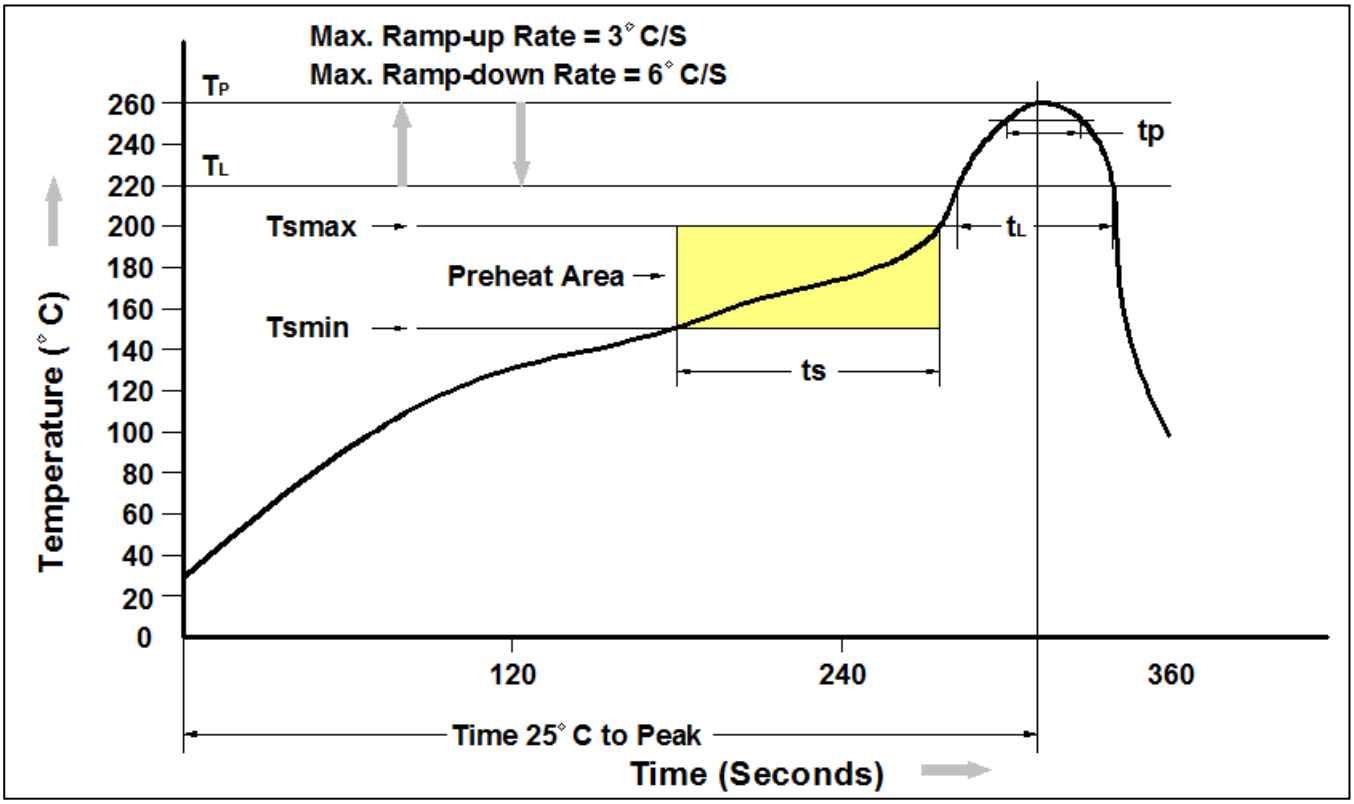
Option SLM(T1)



Option SLM(T2)



Reflow Profile



Profile Feature	Pb-Free Assembly Profile
Temperature Min. (Tsmin)	150℃
Temperature Max. (Tsmax)	200℃
Time (ts) from (Tsmin to Tsmax)	60-120 seconds
Ramp-up Rate (t_L to t_P)	3℃/second max.
Liquidous Temperature (T_L)	217℃
Time (t_L) Maintained Above (T_L)	60 – 150 seconds
Peak Body Package Temperature	260℃ +0℃ / -5℃
Time (t_P) within 5℃ of 260℃	30 seconds
Ramp-down Rate (T_P to T_L)	6℃/second max
Time 25℃ to Peak Temperature	8 minutes max.

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2. *A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.*